



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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Re the Application of: **EMA, Taiji**

Group Art Unit: 2815

Serial No.: 09/050,113

Examiner: **WARREN, Matthew E.**

Filed: **March 30, 1998**

P.T.O. Confirmation No.: 6454

For: **SEMICONDUCTOR DEVICE INCLUDING CONTACT HOLES BETWEEN
ADJACENT CONDUCTOR PATTERNS AND METHOD FOR FABRICATING THE
SAME**

AMENDMENT UNDER 37 CFR §1.111

Commissioner for Patents
Washington, D.C. 20231

February 3, 2003

Sir:

In response to the Office Action dated **October 2, 2002**, extended to **February 2, 2003** by
a one-month Petition for Extension of Time, please amend the above-identified application as
follows:

IN THE CLAIMS:

AMEND claims 2 and 36 as follows.

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2. (Five Times Amended) A semiconductor device comprising:
- a base substrate;
 - a first conducting film formed over the base substrate and including a plurality of conductor patterns adjacent to each other;
 - an etching stopper film covering an upper surface of the conductor patterns;
 - a contact hole located in a part of a region between the adjacent conductor patterns and having an end thereof defined by the conductor patterns;

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